NSN 5961-00-304-8503

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-304-8503

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.120 inches all semiconductor device diode and 0.200 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode and 1.500 inches all semiconductor device diode

Overall Diameter:

0.055 inches all semiconductor device diode and 0.090 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

5.1 regulator voltage all semiconductor device diode

Voltage Tolerance In Percent:

-2.0/+2.0 all semiconductor device diode

Current Rating Per Characteristic:

20.00 milliamperes all primaries horsepower metric all semiconductor device diode

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0